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FDH45N50F N-Channel UniFETTM FRFET[®] MOSFET **500 V, 45 A, 120 m**Ω

Features

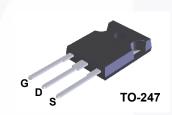
- R_{DS(on)} = 105 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 22.5 A
- Low Gate Charge (Typ. 105 nC)
- Low C_{rss} (Typ. 62 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability

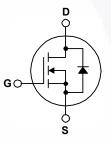
Applications

- Lighting
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. The body diode's reverse recovery performance of UniFET FRFET® MOSFET has been enhanced by lifetime control. Its trr is less than 100nsec and the reverse dv/dt immunity is 15V/ns while normal planar MOSFETs have over 200nsec and 4.5V/nsec respectively. Therefore, it can remove additional component and improve system reliability in certain applications in which the performance of MOSFET's body diode is significant. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		FDH45N50F_F133	Unit	
V _{DSS}	Drain-Source Voltage		500	V
ID	Drain Current	- Continuous (T _C = 25°C) - Continuous (T _C = 100°C)	45 28.4	A A
I _{DM}	Drain Current	- Pulsed (Note 1)	180	А
V _{GSS}	Gate-Source voltage		±30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2		1868	mJ
I _{AR}	Avalanche Current (Not		45	А
E _{AR}	Repetitive Avalanche Energy (Note 1)		62.5	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		50	V/ns
P _D	Power Dissipation	(T _C = 25°C) - Derate Above 25°C	625 5	W W/°C
T _{J,} T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C

Thermal Characteristics

Symbol	Parameter	FDH45N50F_F133	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.2	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	40	°C/W	

November 2013

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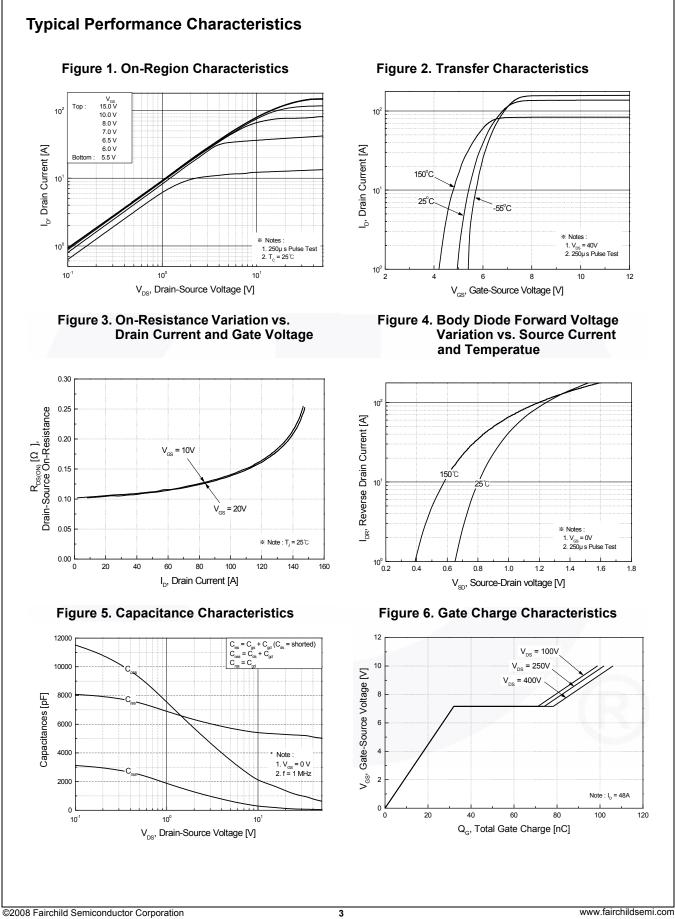
Part Number Top Mark		Package Packing Method		Reel Si	ze	Tape Wid	ith C	Quantity	
FDH45N50F_F133 FDH45N50F		TO-247 Tube N/A		N/A	N/A 30 u		30 units		
Electric	al Chara	cteristics T _C = 25°C	cunless othe	rwise noted.					
Symbol		Parameter		Conditions		Min.	Тур.	Max	Unit
Off Charac	teristics						•		
BV _{DSS}	Drain-Sourc	e Breakdown Voltage	V _{GS} = 0 \	V _{GS} = 0 V, I _D = 250 μA		500			V
ΔBV_{DSS} / ΔT_{J}	Breakdown Coefficient	Voltage Temperature	$I_D = 250 \ \mu\text{A}$, Referenced to 25°C			0.5		V/°C	
I _{DSS}	Zero Gate Voltage Drain Current		$V_{DS} = 500 V, V_{GS} = 0 V$ $V_{DS} = 400 V, T_{C} = 125^{\circ}C$				25 250	μΑ μΑ	
I _{GSSF}	Gate-Body I	eakage Current, Forward	V _{GS} = 30	V, V _{DS} = 0 V		-		100	nA
I _{GSSR}	Gate-Body I	_eakage Current, Reverse	V _{GS} = -30	0 V, V _{DS} = 0 V				-100	nA
On Charac	teristics								
V _{GS(th)}	Gate Threshold Voltage		$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$		3.0		5.0	V	
R _{DS(on)}		atic Drain-Source $V_{GS} = 10 \text{ V}, I_D = 22.5 \text{ A}$			0.105	0.12	Ω		
9 _{FS}	Forward Transconductance V_{DS} = 40 V, I _D = 22.5 A		V, I _D = 22.5 A		-	49.0		S	
Dynamic C	haracteristic	s							
C _{iss}	Input Capac	itance		V, V_{GS} = 0 V,			5100	6630	pF
C _{oss}	Output Capa	acitance	f = 1 MHz	f = 1 MHz			790	1030	pF
C _{rss}	Reverse Tra	ansfer Capacitance	-			62		pF	
C _{oss}	Output Capa	acitance	V _{DS} = 40	V _{DS} = 400 V, V _{GS} = 0 V, f = 1 MHz			161		pF
C _{oss(eff.)}	Effective Ou	tput Capacitance	$V_{DS} = 0 V \text{ to } 400 V, V_{GS} = 0 V$			342		pF	
	Characterist	ics							
t _{d(on)}	Turn-On De	lay Time	V _{DD} = 25	V _{DD} = 250 V, I _D = 48 A,			140	290	ns
t _r	Turn-On Ris	e Time	V_{GS} = 10 V, R_{G} = 25 Ω			500	1010	ns	
t _{d(off)}	Turn-Off De	lay Time		-			215	440	ns
t _f	Turn-Off Fal	l Time			(Note 4)		245	500	ns
Qg	Total Gate C	Charge		$V_{DS} = 400 \text{ V}, \text{ I}_{D} = 48 \text{ A},$ $V_{GS} = 10 \text{ V}$			105	137	nC
Q _{gs}	Gate-Source	e Charge	V _{GS} = 10				33		nC
Q _{gd}	Gate-Drain	Charge	(Note 4)			45		nC	
	ce Diode Ch	aracteristics and Maximu	m Ratings						1
I _S	Maximum Continuous Drain-Source Dio		ode Forward Current				45	Α	
I _{SM}	Maximum Pulsed Drain-Source Diode F		Forward Current				180	Α	
V _{SD}	Drain-Sourc	e Diode Forward Voltage	V _{GS} = 0 \	/, I _S = 45 A				1.4	V
t _{rr}	Reverse Re	covery Time		/, I _S = 45 A,			188		ns
Q _{rr}	Reverse Re	covery Charge	$dI_F/dt = 10$				0.64		μC

Notes:

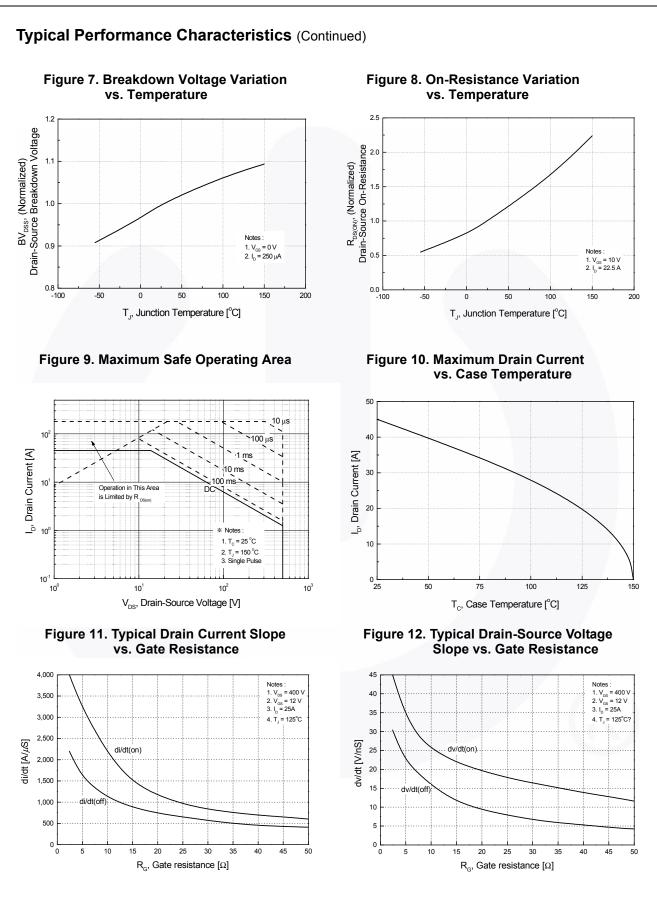
1. Repetitive rating: pulse-width limited by maximum junction temperature.

2. L = 1.46 mH, I_{AS} = 48 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} ≤ 45 A, di/dt ≤ 200 A/µs, V_{DD} ≤ BV_{DSS}, starting T_J = 25°C.

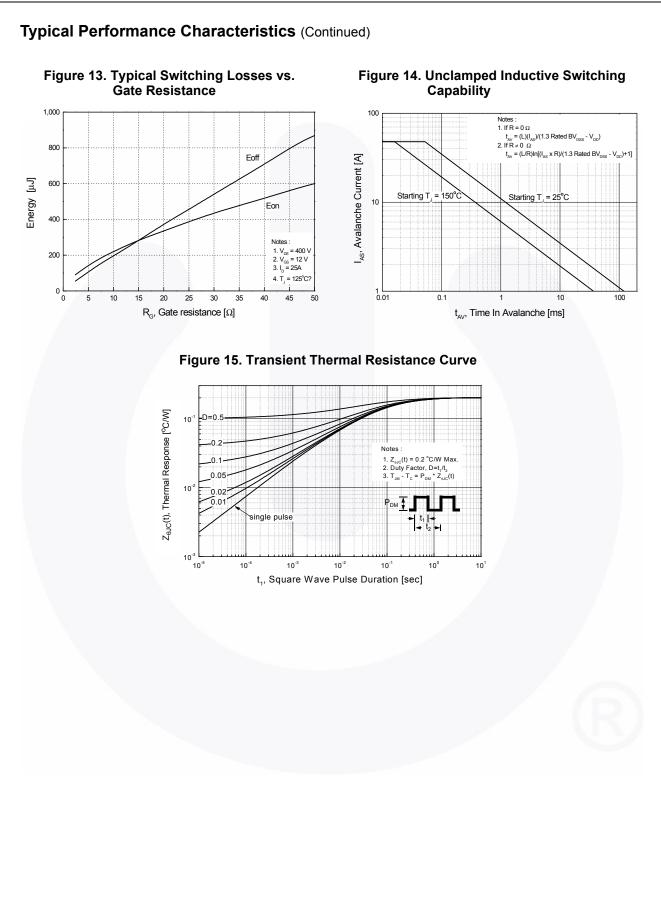
4. Essentially independent of operating temperature typical characteristics.



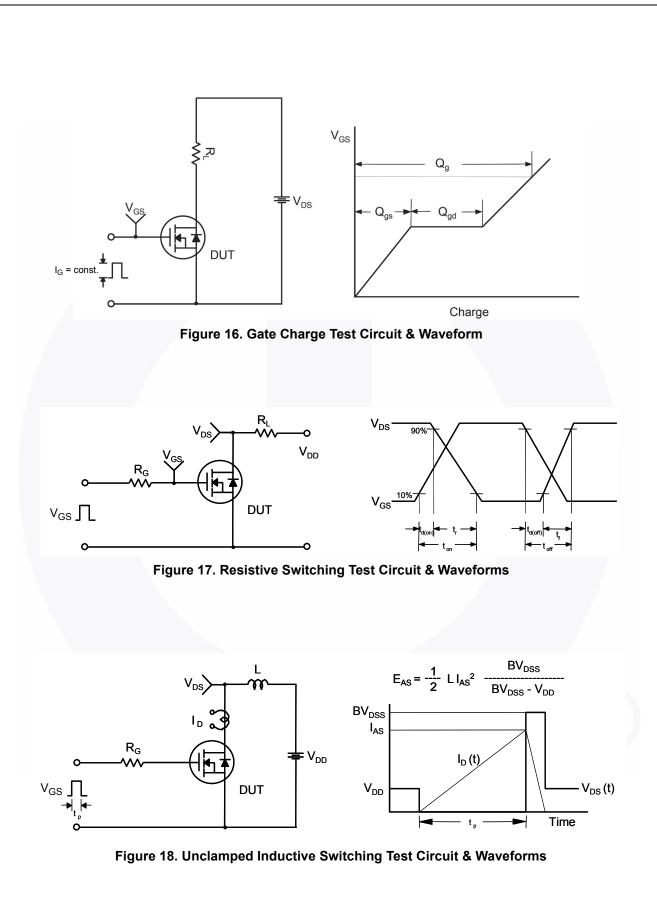
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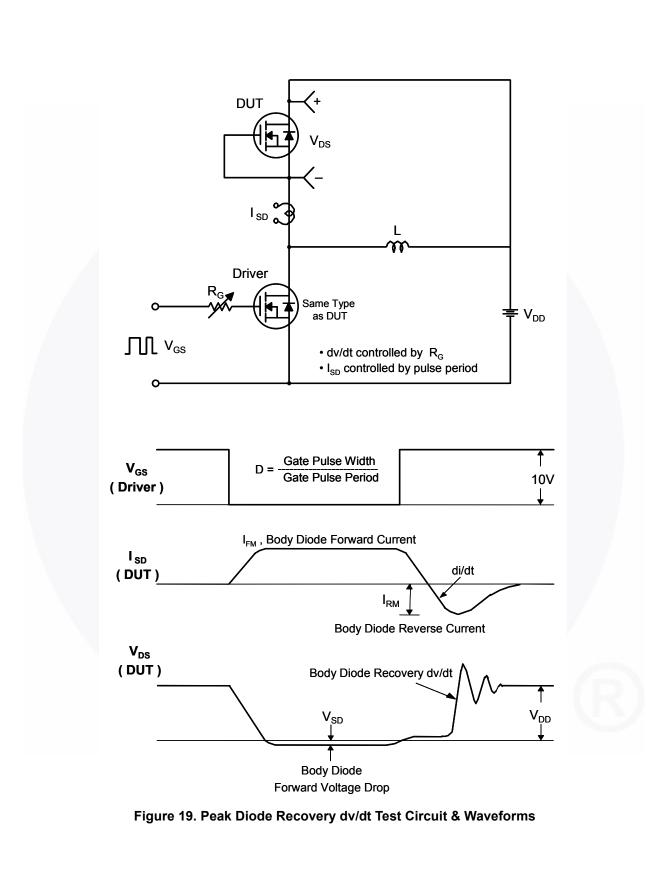
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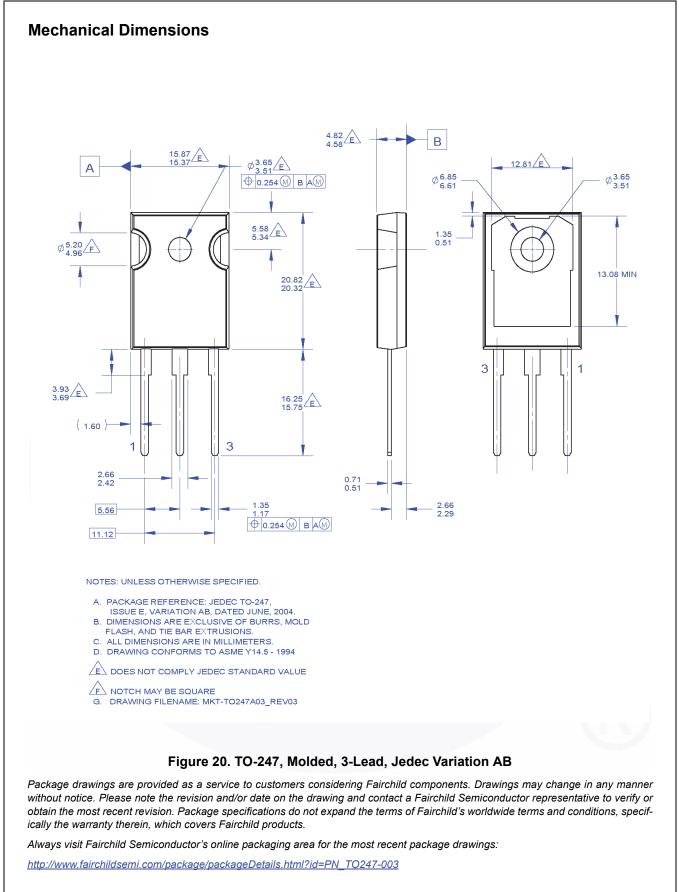


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FDH45N50F — N-Channel UniFETTM FRFET[®] MOSFET







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